

One-step Convenient Hydrothermal Synthesis of MoS₂/RGO as a High-performance Anode for Sodium-ion Batteries

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A molybdenum disulfide (MoS₂) nanosheet was grown directly on a surface of reduced graphene oxide (RGO) by using a one-step hydrothermal growth technique. The samples were systematically characterized by using X-ray diffraction (XRD), field-emission scanning electron microscopy (FE-SEM) and high-resolution transmission electron microscopy (HRTEM). The electrochemical properties were evaluated by cyclic voltammetry, galvanostatic charge/discharge and electrochemical impedance spectroscopy tests in two-electrode cells. The results indicate that the synthesized MoS₂/RGO composites show excellent electrochemical performance as anode materials for Na-ion batteries. The MoS₂/RGO composites exhibit an initial discharge capacity of 715.5 mAh g⁻¹ and an initial charge capacity of 440.5 mAh g⁻¹ at a current density of 100 mA g⁻¹. The composites also exhibit excellent cycling stability with almost no capacity fading after 100 cycles at a current density of 250 mA g⁻¹ compared with only 39.6% of that for pure MoS₂, and the electrode shows stable high-rate performance. The superior electrochemical performance of the MoS₂/RGO composites as Na-ion battery anodes may be attributed to their loose structure and the excellent conductivity of reduced graphene oxide in MoS₂/RGO.

Keywords: MoS₂/RGO composites; hydrothermal synthesis; anode material; sodium-ion battery

1. INTRODUCTION

Due to the scarcity of lithium, there are clear and compelling economic and practical drivers to explore alternatives to lithium ions in charge storage devices[1,2,3]. Sodium-ion batteries (SIBs) have many advantages due to the intrinsic advantages of sodium, for example, they are environmentally benign, easy to recover, inexpensive and relatively abundant[4,5,6]. However, the larger ion radius and

transport barrier restrict the choice of electrode materials for SIBs[7,8]. Therefore, it is of great importance to explore a suitable host for SIBs.

Molybdenum disulfide (MoS_2) has a similar layered structure to graphite, in which each layer has a slab of transition metal atoms sandwiched by two slabs of chalcogenide atoms. Covalent bonds are formed between Mo and S within each layer and the Mo-S polyhedron can be described as a trigonal prism where Mo^{4+} is in the centre of the prism[9,10]. In the structure, adjacent MoS_2 layers are interconnected with weak van der Waals forces, and there is sufficient space between the layers to host alkali metal ions during charging, which suggests the possibility of MoS_2 as a potential electrode material for high-capacity rechargeable batteries. However, bulk MoS_2 possesses low conductivity and suffers from large volume expansion and pulverization when used as an anode material, which render poor cycle performance and poor rate capability[9,11]. To overcome these problems and improve the electrochemical properties of MoS_2 , various strategies have been proposed, and one effective approach is to design composites with a matrix that can act as a buffer layer for volume expansion during charge-discharge processes[11,12,13,14]. Among those materials, graphene sheets have been considered as a potential matrix material to improve the electrochemical performance of MoS_2 due to their extraordinary electronic transport properties, large surface area and mechanical flexibility[15,16].

Previous studies have synthesized MoS_2/G by various methods, and most of the methods contain complex steps[17,18]. To modify the interlayer structure of MoS_2 and accelerate both electron and ion transport in a simple way, we produced layered MoS_2/RGO composites using a one-step hydrothermal method. The results demonstrated that the obtained MoS_2/RGO composites show excellent electrochemical performance as anode materials for sodium-ion batteries compared with bulk MoS_2 due to the synergistic effects between layered MoS_2 and graphene. The MoS_2/RGO composites present a high rate stability and an excellent cycling stability with almost no capacity fading after 100 cycles at a current density of 250 mA g^{-1} .

2. EXPERIMENTAL

2.1 Synthesis of the MoS_2/RGO composites

Graphene oxide (GO, 20 mg) synthesized by a modified Hummers method was dispersed in 60 ml of ultrapure water under vigorous ultrasonic agitation to form a homogeneous solution. Then, 1.5 g of sodium molybdate and 1.9 g of thiourea were added into the above dispersion successively. After ultrasonication and stirring for 20 min, the solution was transferred into a 100 ml Teflon-lined stainless steel autoclave, sealed tightly and then hydrothermally treated at 180°C for 24 h. After cooling naturally, the resulting black precipitate was collected by filtering and washing with ultrapure water and absolute ethanol for several times and dried in a vacuum oven at 80°C for 12h. Then, the MoS_2/RGO composites were obtained. For comparison, MoS_2 was also synthesized through similar procedures without adding GO.

2.2 Material characterization

X-ray diffractometer (Bruker D-8) (Cu K α , $\lambda=0.154056$ nm) was applied to study the phase structure of samples. Field emission scanning electron microscopy (FESEM, JSM-6360LV, JEOL) and high-resolution transmission electron microscopy (HRTEM, Tecnai G2F20 S-TWIX) were used to determine the morphology of the as-prepared composites. Raman spectra (LabRAM HR800) were obtained with a laser excitation of 532 nm.

2.3 Electrochemical measurements

The electrochemical properties were studied by using two-electrode cells that were assembled in an argon-filled glove box. The electrodes were prepared by mixing the prepared active material, acetylene black and sodium alginate (7:2:1 wt/wt/wt) in water to obtain a uniform slurry. The slurry was coated onto a copper foil and dried in a vacuum oven at 80 °C overnight. The CR2032 coin cells were assembled in an argon-filled glove box using a glass microfibre (Whatman) membrane and sodium metal foil as the separator and counter electrodes, respectively. The electrolyte was a mixture of 1 M NaClO₄ in EC/DMC (1:1, v/v) with 5 wt% fluoroethylene carbonate (FEC). Galvanostatic charge/discharge measurements were carried out in the voltage range of 0.01 ~ 3.00 V on a battery tester at various current densities. Cyclic voltammetry measurements were performed on an electrochemical workstation within the voltage range of 0.01-3.00 V at a scan rate of 0.2 mV/s. Electrochemical impedance spectroscopy (EIS) data were measured applying a 5 mV amplitude signal in the frequency range of 100 kHz to 0.01 Hz. The specific capacity of the electrode was calculated based on the total mass of MoS₂/RGO synthesized in the experiment.

3. RESULTS AND DISCUSSION

The XRD patterns of pure MoS₂ and MoS₂/RGO are presented in Figure 1. As shown in the Figure, MoS₂ exhibits high crystallinity, and the diffraction peaks observed at 14.1°, 33.3°, 44.4° and 58.65° correspond to different crystal planes of hexagonal MoS₂, which is in accordance with those established by JCPDS card number 37-1492[19,20,21]. The strong peak at 14.1° corresponds to the (002) plane with a d-spacing of 0.63 nm, indicating that layered MoS₂ grows well along the c axis during synthesis[11]. In addition, the MoS₂/RGO composites basically retain the layered crystallinity and the position of the diffraction peaks of MoS₂[18]. However, it is worth noting that the intensity of the (002) plane peak of MoS₂ decreases with the addition of graphene in the composites, which indicates that the incorporation of the graphene considerably inhibits the (002) plane growth of MoS₂ crystals in the composites. Additionally, the XRD pattern of the MoS₂/RGO composites shows that the (002) diffraction peak of the graphene nanosheets cannot be detected, indicating that the graphene nanosheets do not stack during the hydrothermal process[18].

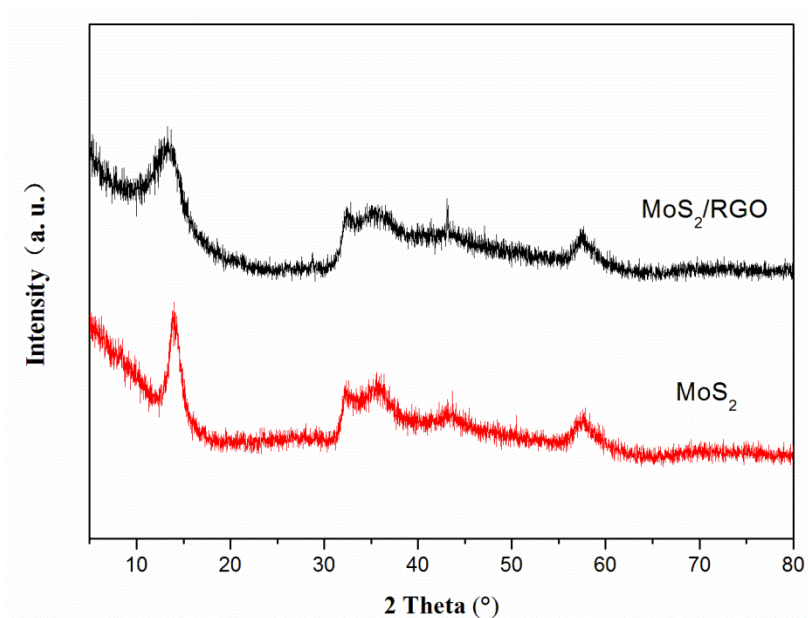
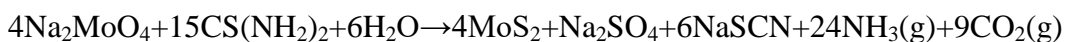


Figure 1. XRD patterns of pure MoS₂ and MoS₂/RGO

The morphologies of MoS₂ and MoS₂/RGO are characterized using SEM. It can be seen from Figure 2 that bare MoS₂ obtained through the proposed method aggregates severely and consists of large-scale sheets that are tightly stacked together. A nucleation of MoS₂ occurs during the hydrothermal process, and a subsequent accumulation occurred directly on the substrate surface. Moreover, increases in the reaction time turned MoS₂ nucleation into a nanosheet-like structure, and the addition of GO highly affects the morphology of the material. When GO was predisposed in the hydrothermal solution, the microsized MoS₂/RGO composites displayed a loose 3D architecture morphology consisting of a large number of scaled and curved sheets, as shown in Figure 2b. The 3D architecture of the MoS₂/RGO composites was caused by graphene self-assembling during the hydrothermal process, in which GO was reduced to graphene, and the flexible graphene self-assembled into a 3D architecture by partial overlapping or coalescing of the sheets[18]. It is demonstrated that MoO₄²⁻ was reduced to MoS₂ by thiourea, and GO was reduced to graphene simultaneously during the hydrothermal process. Thiourea plays the role of a reducing agent and a sulfur donor during the hydrothermal process[22,23,24].



During this process, the GO or reduced GO nanosheets could be used as a novel substrate for the nucleation and subsequent growth of MoS₂[25]. The growth of MoS₂ is mainly selective on GO, attributing to the interaction between the oxygen-containing functional groups on the GO sheets and Mo precursors[26]. Due to the layered MoS₂ growth on surface of GO or reduced GO, the stacking of the graphene was inhibited during the hydrothermal process. Meanwhile, the incorporation of the reduced graphene oxide also restrained the (002) plane growth of the MoS₂ crystals in the composites[18].

Three-dimensional architectural MoS₂/RGO composites as NIB anodes will increase the contact area between the material and electrolyte, and provide more and shorter Na-ion diffusion paths

during the intercalation/deintercalation processes. In addition, the overlapping or coalescing of the graphene will form an interconnected conducting network, which is very important for the less-conducting MoS₂ as electrode materials, and facilitate rapid electronic transport during electrode reactions[18]. Finally, this 3D structure also enhances the stability of the MoS₂/RGO composites due to the super strength of graphene.

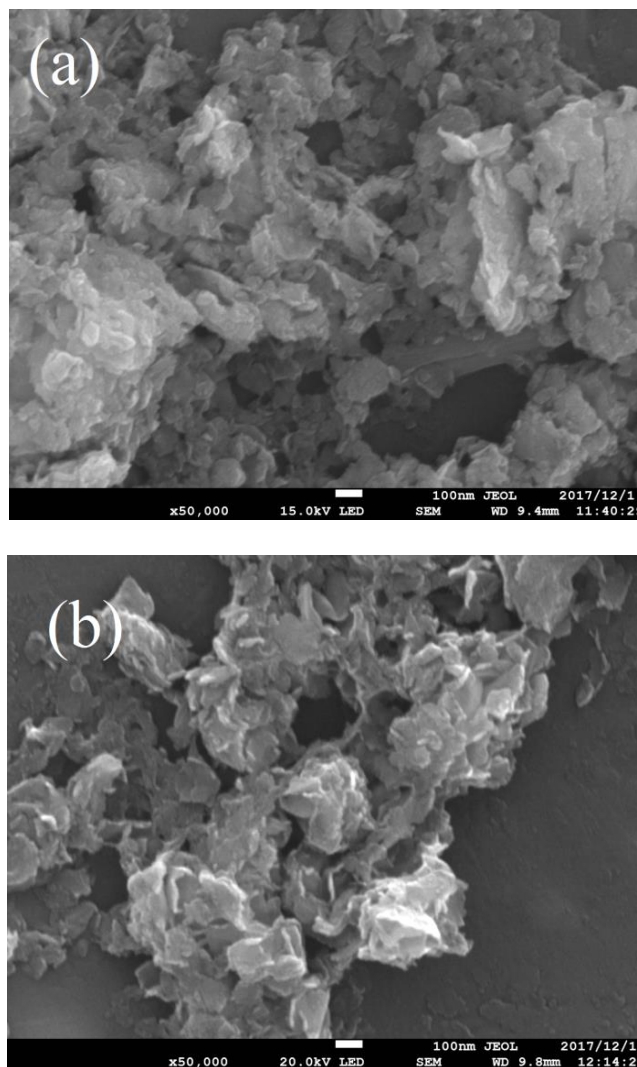


Figure 2. SEM images of MoS₂ (a) and MoS₂/RGO (b)

Subsequently, we have analysed the microstructure of the MoS₂/RGO sample in detail with high-resolution transmission electron microscopy (HRTEM), as shown in Figure 3. From Figure 3a, it can be clearly seen that layered MoS₂/RGO shows a flower-like morphology, and the MoS₂/RGO nanosheets are only a few atomic layers in thickness with an interlayer distance of 0.63 nm (Figure 3b), while pure MoS₂ shows dozens of atomic layers (Figure 3c). This few-atomic-layer thick structure is beneficial for the fast kinetics of the intercalation/deintercalation of sodium ions[11]. The selected-area electron diffraction pattern is shown in Figure 3d, and it is well-indexed as a pure hexagonal MoS₂ phase.

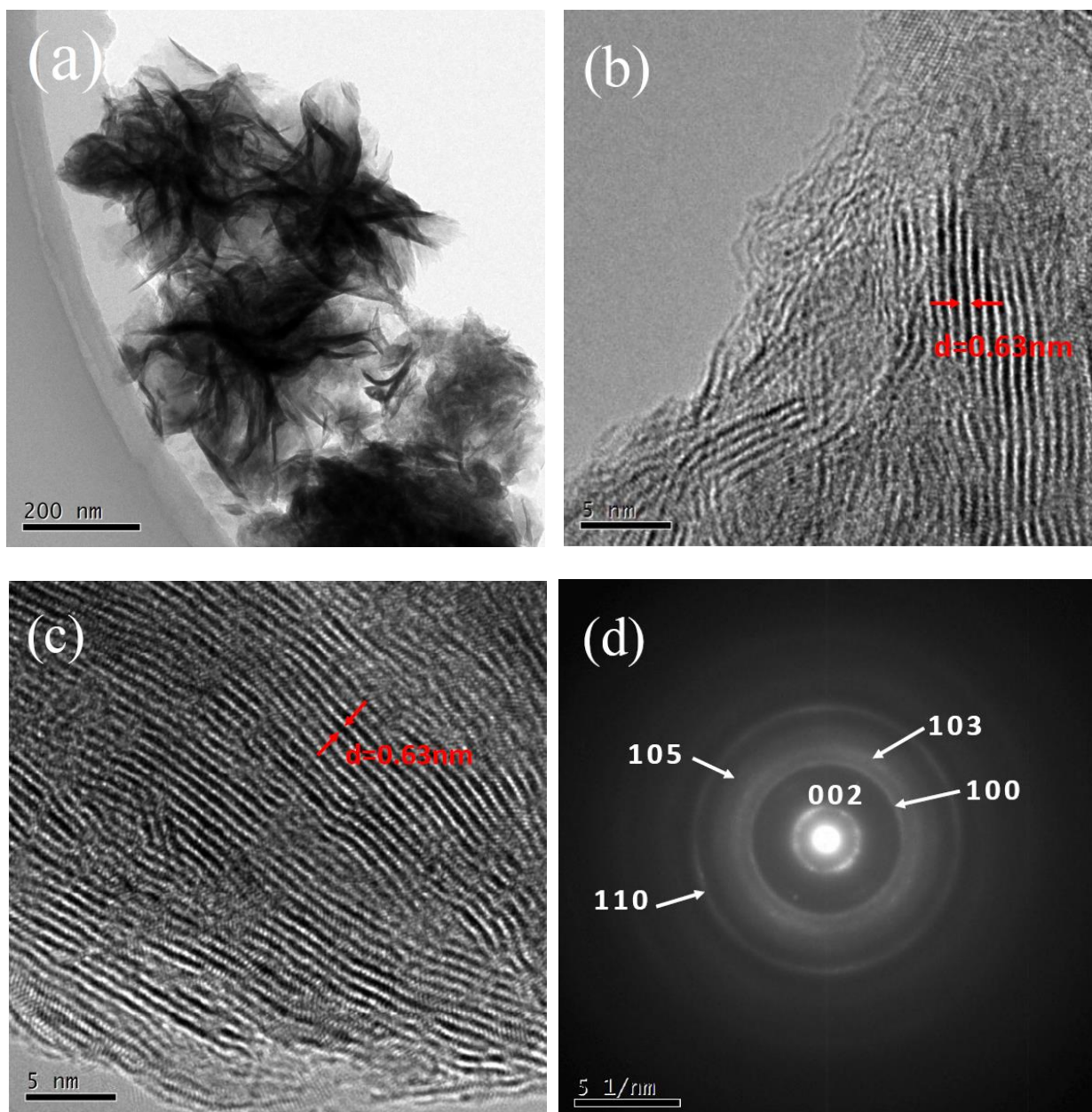


Figure 3. TEM images of MoS₂/RGO (a,b) and pure MoS₂ (c); Electron diffraction pattern of MoS₂/RGO (d)

The Raman spectra of MoS₂ and MoS₂/RGO are displayed in Figure 4. Two distinct peaks centred at approximately 1360 cm^{-1} and 1590 cm^{-1} in Raman spectra of MoS₂/RGO arise from disordered and graphic carbon further and demonstrates the existence of graphene in MoS₂/RGO[11,27]. Two other characteristic peaks located at approximately 375 cm^{-1} and 405 cm^{-1} that correspond to MoS₂ are well distinguished[11]. In addition, two distinct peaks of pure MoS₂ are detected in the Raman spectra, while the widened diffraction peak at approximately 1590 cm^{-1} may come from carbon residue in thiourea, which is in good accordance with the synthesis process.

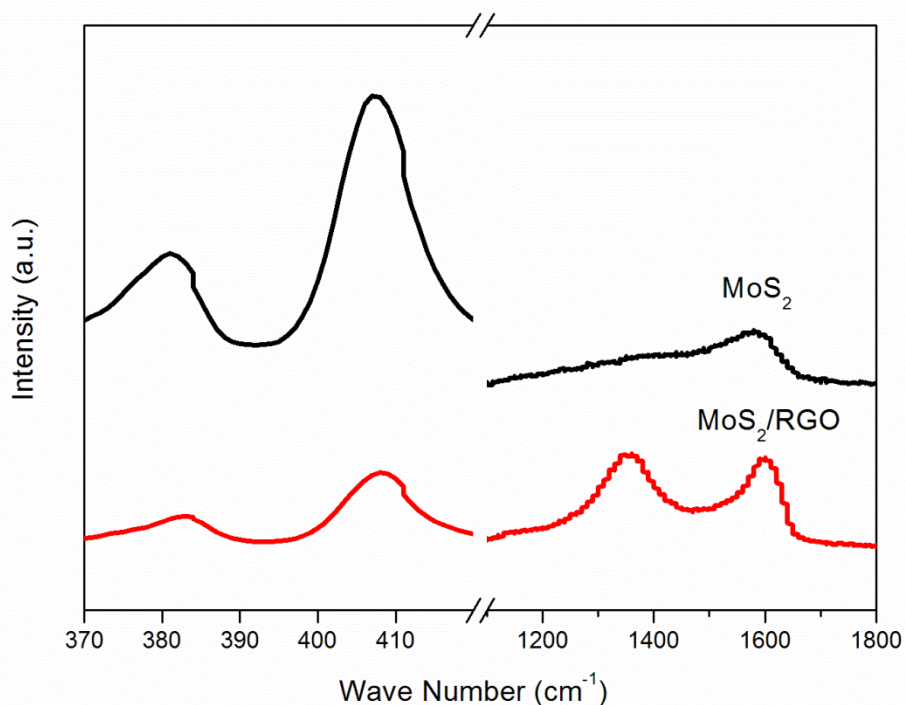


Figure 4. Raman spectra of MoS₂ and MoS₂/RGO

Experimental characterization revealed that the MoS₂/RGO composites exhibit a composite structure of layered MoS₂ and graphene. Then, the electrochemical behaviours of MoS₂/RGO are first evaluated by cyclic voltammetry (CV) measurements. As displayed in Figure 5a, the peak located at approximately 0.80 V in the first cycle corresponds to the insertion of Na⁺ into MoS₂ and formation of an SEI (solid electrolyte interphase) layer. In addition, the peak located at approximately 0.1 V can be attributed to the formation of Mo and Na₂S. The anodic peak located at approximately 1.8 V is attributed to oxidation reaction from Mo to MoS₂[11]. The anodic curves during subsequent cycles show similar characteristics to that of the first cycle, while the cathodic curves show differences, which can be attributed to the formation of an SEI film at the first cycle[11]. The CV curves at the third cycle are similar to those at the second cycle, demonstrating the good reversibility of the MoS₂/RGO composite.

Figure 5b illustrates the first three charge and discharge curves of the synthesized MoS₂/RGO composites at a current density of 100 mA g⁻¹. These curves illustrate that the initial discharge capacity of MoS₂/RGO is 715.5 mAh g⁻¹, and the initial charge capacity is 440.5 mAh g⁻¹. It can be seen from the curves that two potential plateaus at approximately 1.2 V and 0.2 V are observed for the synthesized MoS₂/RGO electrode during the first discharge process, and one plateau at 1.8 V in the first charge process is observed. The charge-discharge profiles curves in the third cycle are similar to those during the second cycle, which also demonstrates good reversibility of the MoS₂/RGO composites. These results are in good agreement with the CV results. These observations are in concert with former results[11,28]. The slightly lower reductive peak of 0.80 V in the CV curves compared with that of 1.2 V in first charge-discharge profile may come from a larger current and subsequently a larger polarity during the CV measurement.

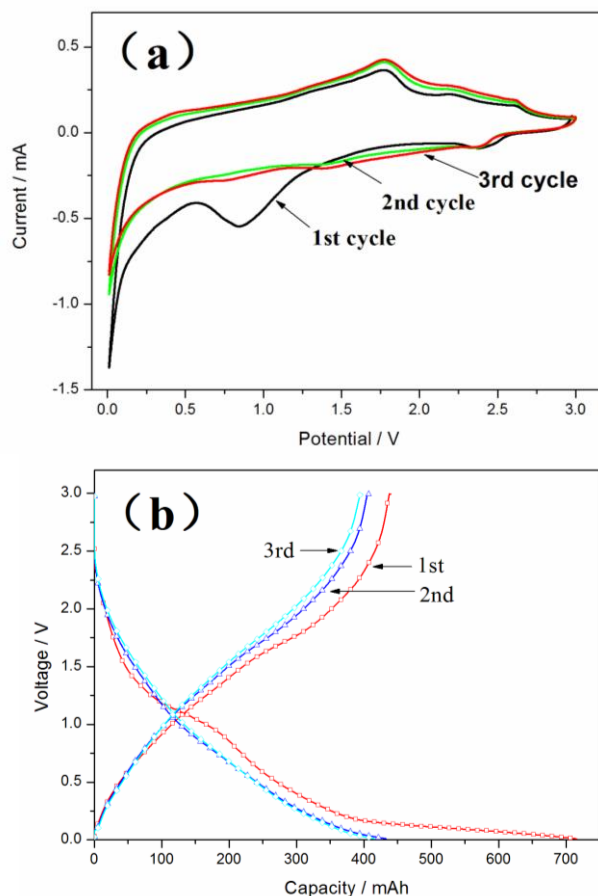


Figure 5. Cyclic voltammetry curves of the MoS₂/RGO (a) and the first three charge and discharge curves of MoS₂/RGO (b)

The cycling performances of the MoS₂ and MoS₂/RGO are tested at a current density of 250 mA g⁻¹ and are illustrated. As shown in Figure 6a, the cyclic stability of MoS₂ is so poor that the reversible capacity decreases to 125 mAh g⁻¹ after 100 cycles, which is only 39.6% of the initial capacity. In contrast, the MoS₂/RGO composites present an excellent cycling stability. The reversible capacity of MoS₂/RGO increases slightly during the initial dozens of cycles with almost no fading after 100 cycles. The result is consistent with earlier studies[26,27]. Thus, the incorporation of graphene largely improves their cyclic stabilities due to the robust composite structure and the synergistic effect between the layered MoS₂ and graphene[18]. In addition, the worse cycling stability of MoS₂ may be because of its tight stacking with each other, thus leading to longer sodium-ion diffusion paths.

The high reversible capacity of the MoS₂/RGO composites is also exhibited in the rate capability. Figure 6b shows the rate behaviour of the composites. At a current density of 250 mA g⁻¹, MoS₂/RGO shows a reversible capacity of 338 mA h g⁻¹. At current densities of 500 and 1000 mA g⁻¹, the reversible capacities are maintained at 280 and 240 mA h g⁻¹, respectively. Even at high current densities of 1500 mA g⁻¹ and 2000 mA g⁻¹, the specific capacities remain at preferred values. When the charge/discharge current density changes from 2000 to 250 mA g⁻¹, the specific capacity of the composites returns to more than 300 mA h g⁻¹, indicating high reversibility.

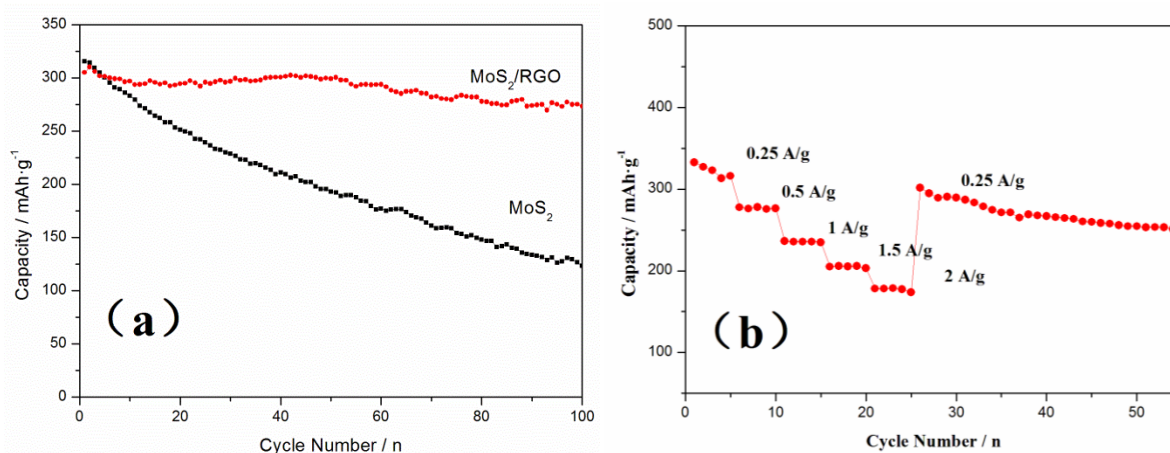


Figure 6. Cycling behaviours of MoS₂ and MoS₂/RGO at a current density of 250 mA g⁻¹ (a) and rate capabilities of a MoS₂/RGO sample at different current densities (b)

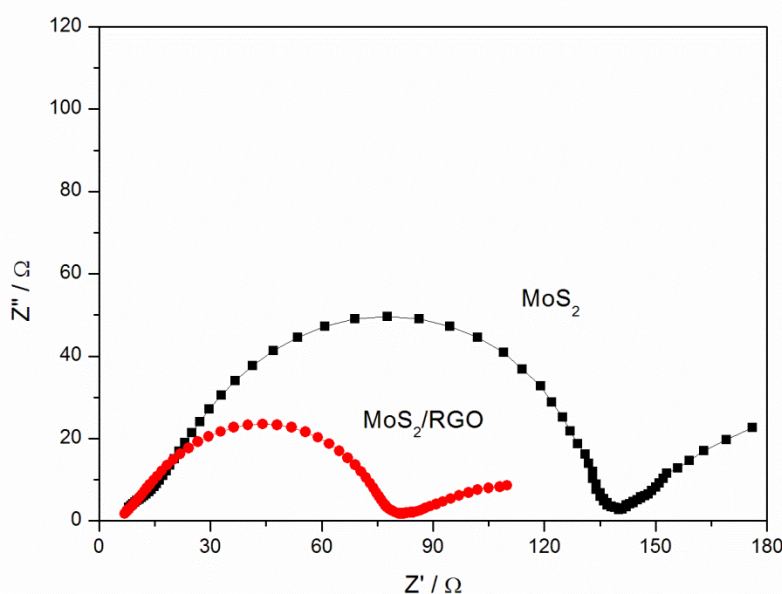


Figure 7. Nyquist plots of MoS₂ and MoS₂/RGO

To understand why the MoS₂/RGO electrode exhibits such a superior electrochemical performance, ac impedance measurements were performed after 3 cycles, as shown in Figure 7. The impedance spectra present a semicircular arc at middle frequencies and a sloped-line-like diffusion behaviour at low frequencies. The depressed semicircular arc is related to the capacitive behaviour with a parallel resistance on the electrode/electrolyte interface, for instance, a double-layer capacitance with a parallel charge transfer resistance and capacitance of an SEI layer in parallel with its resistance[29]. In addition, the inclined line corresponds to a sodium-diffusion process within the bulk of the electrode material. The middle-frequency arc width (R_w) values decrease with the addition of graphene, and the large decrease in R_w can be interpreted as a decrease in the interfacial resistance that is induced by the convenient charge transition on the MoS₂/RGO anode. This fact confirms that the incorporation of graphene can preserve the high conductivity of the MoS₂/RGO composite electrode

and greatly improve rapid electron transport during the electrochemical sodium insertion/extraction reaction, resulting in a significant improvement in the electrochemical performance. Thus, this novel type of MoS₂/RGO composite with a high reversible capacity, excellent cyclic stability, and high-rate capability demonstrates wide applications as promising anode materials for SIBs.

4. CONCLUSIONS

A convenient process was developed to synthesize layered MoS₂/RGO composites by a one-step hydrothermal method. The characterizations demonstrate that layered MoS₂ is generated on the graphene surface, which then forms a MoS₂/RGO composite. The addition of graphene inhibits the growth of layered MoS₂ crystals in the composites. The MoS₂/RGO composites exhibit a 3D architecture morphology consisting of curved nanosheets, which is attributed to the self-assembly of a graphene hydrogel during the hydrothermal process. The electrochemical evaluations reveal that the MoS₂/RGO composite electrode exhibits greater cyclic stability than does a bare MoS₂ electrode. The MoS₂/RGO composites present an excellent cycling stability with almost no capacity fading after 100 cycles at a current density of 250 mA g⁻¹ compared with only 39.6% of that for MoS₂. Even at a high current density of 2000 mA g⁻¹, MoS₂/RGO exhibits an excellent cycling stability. The results confirm that the incorporation of graphene preserves the high conductivity and greatly enhances the electrochemical activity of the MoS₂/RGO composites. The improved performance is because of the looser structure of the composites and the high conductivity of reduced graphene oxide, which can accelerate the ion and electron transport, thus providing a fast kinetics mechanism for the electrochemical reactions. Therefore, the prepared MoS₂/RGO composites and the simple one-step method should be attractive for sodium ion batteries.

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